

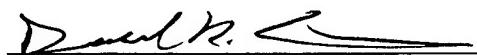
REMARKS

The Official Action dated September 27, 2002 has been received and its contents carefully noted. In view thereof, Applicant hereby elects what the Examiner has indicated as Group I, drawn to a combination classified in class 430, subclass 1+ including at least claims 6-8.

Further with respect to Applicant's response to the Restriction Requirement, as can be seen from the foregoing amendments, claim 5 has been canceled in favor of new claim 18 and claims 6-17 have been amended in order to better define that which Applicant regards as the invention. Further, claims 6-17 now either directly or indirectly depend upon independent claim 18 and include all the limitations thereof. That is, claim 18 is directed to a method for forming a semiconductor device and claims 6-17 are directed to further limitations with respect to the formation of such a semiconductor device. Consequently, it is respectfully submitted that claims 6-17 are now in proper condition for examination in the subject application.

Should the Examiner believe a conference would be of benefit in expediting the prosecution of the instant application, he is hereby invited to telephone counsel to arrange such a conference.

Respectfully submitted,

  
Donald R. Studebaker  
Registration No. 32,815

Nixon Peabody LLP  
8180 Greensboro Drive  
Suite 800  
McLean, Virginia 22102  
(703) 770-9300

Version Showing Changes Made

6. (Amended) The method for forming [an interlayer dielectric film] a semiconductor device of Claim [5] 18, wherein the first cross-linking molecules are first organic molecules having three or more sets of functional groups in one molecule,

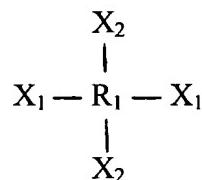
the second cross-linking molecules are second organic molecules having two sets of functional groups in one molecule, and

the three-dimensionally polymerized polymer is formed by 10 binding the three or more sets of functional groups of each of the first organic molecules and the two sets of functional groups of each of the second organic molecules together.

7. (Amended) The method for forming [an interlayer dielectric] a semiconductor device film of Claim 6, wherein

the first organic molecules are represented by

[chemical formula 1]



(where  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups, and  $X_2$  is a second set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic. molecules are represented by

[chemical formula 2]



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a third set of functional groups, and  $Y_2$  is a fourth set of functional groups,  $Y_1$  and  $Y_2$  being same or different. in type),

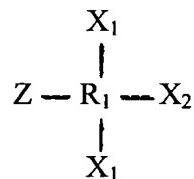
the three-dimensionally polymerized polymer is formed by binding the first set of functional groups ( $X_1$ ) and the third set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fourth set of functional groups ( $Y_2$ ) together, and

[The] the molecular level pores are formed in regions surrounded by the first organic skeletons ( $R_1$ ) and the second organic skeletons ( $R_2$ ).

8. (Amended) The method for forming [an interlayer dielectric film] a semiconductor device of Claim 6, wherein

the first organic molecules are represented by

[chemical formula 3]



(where  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups,  $X_2$  is a second set of functional groups, and  $Z$  is a third set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic molecules are represented by

[chemical formula 4]



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a fourth set of functional groups, and  $Y_2$  is a fifth set of functional groups,  $Y_1$  and  $Y_2$  being same or different in type),

the three-dimensionally polymerized polymer is formed by first binding the first set of functional groups ( $X_1$ ) and the fourth set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fifth set of functional groups ( $Y_2$ ) together to form a

plurality of units and then binding the third [sets] set of functional groups (Z) of the plurality of units together, and

the molecular level pores are formed in regions surrounded by the first organic skeletons ( $R_1$ ) and the second organic skeletons ( $R_2$ ) in the plurality of units.

9. (Amended) [A method for forming an interconnection, comprising the steps of:] The method for forming a semiconductor device of Claim 18, further comprising the steps of:

forming an interlayer dielectric film comprising a three-dimensionally polymerized polymer having a number of molecular level pores inside, by polymerizing first cross-linking molecules having a three-dimensional structure and second cross-linking molecules having a two-dimensional structure;

forming a surface barrier film on the interlayer dielectric film;

forming a mask on the surface barrier film;

forming [an] a concave portion in the surface barrier film and the interlayer dielectric film by etching the surface barrier film and the interlayer dielectric film using the mask; and

forming an interconnection made of a metal material by filling the concave portion with the metal material.

10. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 9, wherein the first cross-linking molecules are first organic molecules having three or more sets of functional groups in one molecule,

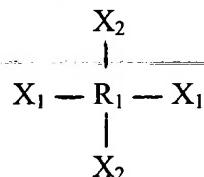
the second cross-linking molecules are second organic molecules having two sets of functional groups in one molecule, and

the three-dimensionally polymerized polymer is formed by binding the three or more sets of functional groups of each of the first organic molecules and the two sets of functional groups of each the second organic molecules together.

11. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 10, wherein

the first organic molecules are represented by

[chemical formula 1]



(where  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups, and  $X_2$  is a second set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic molecules are represented by

[chemical formula 2]



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a third set of functional groups, and  $Y_2$  is a fourth set of functional groups,  $Y_1$  and  $Y_2$  being same or different in type),

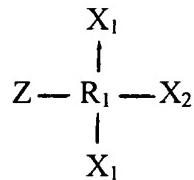
[The] the three-dimensionally polymerized polymer is formed by binding the first set of functional groups ( $X_1$ ) and the third set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fourth set of functional groups ( $Y_2$ ) together, and

[The] the molecular level pores are formed in region surrounded by the first organic skeletons ( $R_1$ ) and the second organic skeletons ( $R_2$ ).

12. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 10, wherein

the first organic molecules are represented by

[chemical formula 3]



(where  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups,  $X_2$  is a second set of functional groups, and  $Z$  is a third set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic molecules are represented by

[chemical formula 4]



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a fourth set of functional groups, and  $Y_2$  is a fifth set of functional groups,  $Y_1$  and  $Y_2$  being same or different in type),

the three-dimensionally polymerized polymer is formed by first binding the first set of functional groups ( $X_1$ ) and the fourth set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fifth set of functional groups ( $Y_2$ ) together to form a plurality of units and then binding the third [sets] set of functional groups ( $Z$ ) of the plurality of units together, and

the molecular level pores are formed in regions surrounded by the first organic skeletons ( $R_2$ ) in the plurality of units.

13. (Amended) [A method for forming an interconnection, comprising the steps

of:] The method for forming a semiconductor device of Claim 18, further comprising the steps of:

forming an interlayer dielectric film comprising a three-dimensionally polymerized polymer having a number of molecular level pores inside, by polymerizing first cross linking molecules having a three-dimensional structure and second cross-linking molecules having a two-dimensional structure;

forming a mask on the interlayer dielectric film;

forming [an] a concave portion in the interlayer dielectric film by etching the interlayer dielectric film using the mask;

forming a sidewall barrier film on sidewalls of the concave portion; and

forming an interconnection made of a metal material by filling the concave portion having the sidewall barrier film with the metal material.

14. (Amended) The method for [forming an interconnection] a semiconductor device of Claim 13, further comprising the step of forming a surface barrier film on the [interlayer dielectric film] a semiconductor device between the step of forming an interlayer dielectric film and the step of forming a mask,

wherein the step of forming an concave portion comprises the step of forming a concave portion in the surface barrier layer and the interlayer dielectric film by etching the surface barrier film and the interlayer dielectric film using the mask.

15. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 13, wherein the first cross-linking molecules are first organic molecules having three or more sets of functional groups of one molecules,

the second cross-linking molecules are second organic molecules having

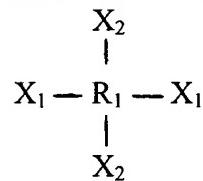
two sets of functional groups in one molecules, and

the three-dimensionally polymerized polymer is formed by binding the three or more sets of functional groups of each of the first organic molecules and the two sets of functional groups of each of the second organic molecules together.

16. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 15, wherein

the first organic molecules are represented by

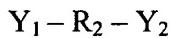
[chemical formula 1]



(wherein  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups, and  $X_2$  is a second set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic molecules are represented by

[chemical formula 2]



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a third set of functional groups, and  $Y_2$  is a fourth set of functional groups,  $Y_1$  and  $Y_2$  being same or different in type),

[The] the three-dimensionally polymerized polymer is formed by binding the first set of functional groups ( $X_1$ ) and the third set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fourth set of functional groups ( $Y_2$ ) together, and

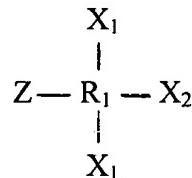
[The] the molecular level pores are formed in region surrounded by the

first organic skeletons ( $R_1$ ) and the second organic skeletons ( $R_2$ ).

17. (Amended) The method for forming [an interconnection] a semiconductor device of Claim 15, wherein

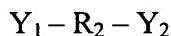
the first organic molecules are represented by

[chemical formula 3]



(wherein  $R_1$  is a first organic skeleton,  $X_1$  is a first set of functional groups,  $X_2$  is a second set of functional groups, and  $Z$  is a third set of functional groups,  $X_1$  and  $X_2$  being same or different in type),

the second organic molecules are represented by



(where  $R_2$  is a second organic skeleton,  $Y_1$  is a fourth set of functional groups, and  $Y_2$  is a fifth set of functional groups,  $Y_1$  and  $Y_2$  being same or different in type),

the three-dimensionally polymerized polymer is formed by first binding the first set of functional groups ( $X_1$ ) and the fourth set of functional groups ( $Y_1$ ) together and binding the second set of functional groups ( $X_2$ ) and the fifth set of functional groups ( $Y_2$ ) together to form a plurality of units and then binding the third [sets] set of functional groups ( $Z$ ) of the plurality of units together, and

the molecular level pores are formed in regions surrounded by the first organic skeletons ( $R_1$ ) and the second organic skeletons ( $R_2$ ) in the plurality of units.